





With 3-State Outputs









SN74LVC4245A

SCAS375I - MARCH 1994-REVISED JANUARY 2015 SN74LVC4245A Octal Bus Transceiver and 3.3-V to 5-V Shifter

Features

- **Bidirectional Voltage Translator**
- 5.5 V on A Port and 2.7 V to 3.6 V on B Port
- Control Inputs V_{IH}/V_{IL} Levels Are Referenced to V_{CCA} Voltage
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model
 - 200-V Machine Model
 - 1000-V Charged-Device Model

Applications

- **ATCA Solutions**
- **CPAP Machines**
- Cameras: Surveillance Analog
- Chemical or Gas Sensors
- **CT Scanners**
- DLP 3D Machine Vision and Optical Networking
- Digital Signage
- ECGs: Electrocardiograms
- Field Transmitters: Pressure Sensors and Temperature Sensors
- High-Speed Data Acquisition and Generation
- HMI (Human Machine Interface)
- **RF4CE Remote Controls**
- Server Motherboards
- Software Defined Radios (SDR)
- Wireless LAN Cards and Data Access Cards
- X-ray: Medical, Dental, and Baggage Scanners

3 Description

This 8-bit (octal) noninverting bus transceiver contains two separate supply rails; B port has V_{CCB}, which is set at 3.3 V, and A port has V_{CCA}, which is set at 5 V. This allows for translation from a 3.3-V to a 5-V environment, and vice versa.

SN74LVC4245A device is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (OE) input can be used to disable the device so the buses are effectively isolated. The control circuitry (DIR, \overline{OE}) is powered by V_{CCA} .

The SN74LVC4245A device terminal out allows the designer to switch to a normal all-3.3-V or all-5-V 20terminal SN74LVC4245 device without board relayout. The designer uses the data paths for pins 2-11 and 14-23 of the SN74LVC4245A device to align with the conventional '245 terminal out.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
	SSOP (24)	8.20 mm × 5.30 mm
SN74LVC4245A	SOIC (24)	15.40 mm × 7.50 mm
	TSSOP (24)	7.80 mm × 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

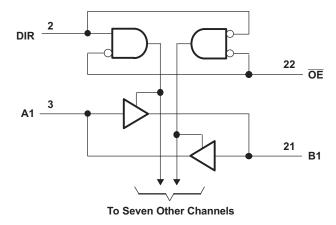




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5 Revision History

Changes from Revision H (March 2005) to Revision I

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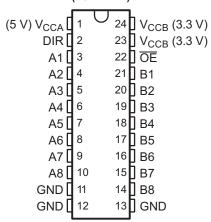
Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table,
Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation
section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and
Mechanical, Packaging, and Orderable Information section.

Deleted Ordering Information table.



6 Pin Configuration and Functions

DB, DW, OR PW PACKAGE (TOP VIEW)



Pin Functions

PIN TYPE		TVDE	DESCRIPTION
NO.	NAME	TTPE	DESCRIPTION
1	V_{CCA}	_	Power supply for side A
2	DIR	I	Direction control
3	A1	I/O	Transceiver I/O pin
4	A2	I/O	Transceiver I/O pin
5	A3	I/O	Transceiver I/O pin
6	A4	I/O	Transceiver I/O pin
7	A5	I/O	Transceiver I/O pin
8	A6	I/O	Transceiver I/O pin
9	A7	I/O	Transceiver I/O pin
10	A8	I/O	Transceiver I/O pin
11	GND	_	Ground
12	GND	_	Ground
13	GND	_	Ground
14	B8	I/O	Transceiver I/O pin
15	B7	I/O	Transceiver I/O pin
16	B6	I/O	Transceiver I/O pin
17	B5	I/O	Transceiver I/O pin
18	B4	I/O	Transceiver I/O pin
19	В3	I/O	Transceiver I/O pin
20	B2	I/O	Transceiver I/O pin
21	B1	I/O	Transceiver I/O pin
22	ŌĒ	I	Output Enable
23	V _{CCB}	_	Power supply for side B
24	V _{CCB}	_	Power supply for side B

Product Folder Links: SN74LVC4245A



7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range for $V_{CCA} = 4.5 \text{ V}$ to 5.5 V (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V_{CCA}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range	A port ⁽²⁾	-0.5	$V_{CCA} + 0.5$	V
		Control inputs	-0.5	6	V
Vo	Output voltage range	A port ⁽²⁾	-0.5	V _{CCA} + 0.5	V
I_{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through each V _{CCA} or GND			±100	mA
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Absolute Maximum Ratings

over operating free-air temperature range for V_{CCB} = 2.7 V to 3.6 V (unless otherwise noted)⁽¹⁾

	1 0	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	,		
			MIN	MAX	UNIT
V_{CCB}	Supply voltage range			4.6	V
V_{I}	Input voltage range	B port ⁽²⁾	-0.5	$V_{CCB} + 0.5$	V
Vo	Output voltage range	B port ⁽²⁾	-0.5	V _{CCB} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through V _{CCB} or GND			±100	mA
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.3 ESD Ratings

PARAMETER		DEFINITION		UNIT
.,	Electrostatic	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	2000	\/
V _(ESD)	discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

⁽²⁾ This value is limited to 6 V maximum.

⁽²⁾ This value is limited to 4.6 V maximum.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.4 Recommended Operating Conditions

for $V_{CCA} = 4.5 \text{ V to } 5.5 \text{ V}^{(1)}$

10. 100,		MIN	MAX	UNIT
V _{CCA}	Supply voltage	4.5	5.5	V
V _{IH}	High-level input voltage	2		V
V _{IL}	Low-level input voltage		0.8	V
V _{IA}	Input voltage	0	V_{CCA}	V
V _{OA}	Output voltage	0	V_{CCA}	V
I _{OH}	High-level output current		-24	mA
I _{OL}	Low-level output current		24	mA
T _A	Operating free-air temperature	-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at the associated V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

7.5 Recommended Operating Conditions

for $V_{CCB} = 2.7 \text{ V to } 3.6 \text{ V}^{(1)}$

			MIN	MAX	UNIT
V _{CCB}	Supply voltage		2.7	3.6	V
V_{IH}	High-level input voltage	V _{CCB} = 2.7 V to 3.6 V	2		V
V_{IL}	Low-level input voltage	V _{CCB} = 2.7 V to 3.6 V		0.8	V
V _{IB}	Input voltage		0	V_{CCB}	V
V _{OB}	Output voltage		0	V_{CCB}	V
	I Park Tarrell and and a comment	V _{CCB} = 2.7 V		-12	A
I _{OH}	High-level output current	V _{CCB} = 3 V		-24	mA
	Law law all autout auroret	V _{CCB} = 2.7 V		12	A
I _{OL}	Low-level output current $V_{CCB} = 3 \text{ V}$			24	mA
T _A	Operating free-air temperature		-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at the associated V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

7.6 Thermal Information

	THERMAL METRIC ⁽¹⁾	DB	DW	PW	UNIT
			24 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	63	46	88	°C/W

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

Product Folder Links: SN74LVC4245A



7.7 Electrical Characteristics

over recommended operating free-air temperature range for V_{CCA} = 4.5 V to 5.5 V (unless otherwise noted)⁽¹⁾

P.A	ARAMETER	TEST CONDITIONS	V _{CCA}	MIN	TYP ⁽²⁾	MAX	UNIT
		100 A	4.5 V	4.3			
V		$I_{OH} = -100 \mu A$	5.5 V	5.3			V
V_{OH}		04.74	4.5 V	3.7			V
		$I_{OH} = -24 \text{ mA}$	5.5 V	4.7			
V _{OL}		1 400 A	4.5 V			0.2	
		$I_{OL} = 100 \mu A$	5.5 V			0.2	V
		1 24 4	4.5 V			0.55	
		I _{OL} = 24 mA	5.5 V			0.55	
I _I	Control inputs	V _I = V _{CCA} or GND	5.5 V			±1	μΑ
I _{OZ} (3)	A port	$V_O = V_{CCA}$ or GND	5.5 V			±5	μΑ
I _{CCA}		$V_I = V_{CCA}$ or GND, $I_O = 0$	5.5 V			80	μΑ
$\Delta I_{CCA}^{(4)}$		One input at 3.4 V, Other inputs at V _{CCA} or GND	5.5 V			1.5	mA
Ci	Control inputs	V _I = V _{CCA} or GND	Open		5		pF
C _{io}	A port	$V_O = V_{CCA}$ or GND	5 V		11		pF

7.8 Electrical Characteristics

over recommended operating free-air temperature range for $V_{CCB} = 2.7 \text{ V}$ to 3.6 V (unless otherwise noted)⁽¹⁾

PAI	RAMETER	TEST C	ONDITIONS	V _{CCB}	MIN	TYP ⁽²⁾	MAX	UNIT
		$I_{OH} = -100 \ \mu A$		2.7 V to 3.6 V	V _{CC} - 0.2			
\/		10 m A		2.7 V	2.2			V
V _{OH}		$I_{OH} = -12 \text{ mA}$		3 V	2.4			V
		$I_{OH} = -24 \text{ mA}$		3 V	2			
V _{OL}		$I_{OL} = 100 \ \mu A$		2.7 V to 3.6 V			0.2	
		I _{OL} = 12 mA		2.7 V			0.4	V
		I _{OL} = 24 mA		3 V			0.55	
$I_{OZ}^{(3)}$	B port	$V_O = V_{CCB}$ or GND		3.6 V			±5	μΑ
I _{CCB}		$V_I = V_{CCB}$ or GND,	I _O = 0	3.6 V			50	μΑ
$\Delta I_{CCB}^{(4)}$		One input at V _{CCB} – 0.6 V,	Other inputs at V_{CCB} or GND	2.7 V to 3.6 V			0.5	mA
C _{io}	B port	$V_O = V_{CCB}$ or GND		3.3 V		11		pF

 $V_{CCA} = 5 V \pm 0.5 V$.

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V_{CCB} = 2.7 V to 3.6 V.
 All typical values are measured at V_{CC} = 5 V, T_A = 25°C.
 For I/O ports, the parameter I_{OZ} includes the input leakage current.
 This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or the associated ...

All typical values are measured at V_{CC} = 3.3 V, T_A = 25°C. For I/O ports, the parameter I_{OZ} includes the input leakage current.

This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or the associated V_{CC} .



7.9 Switching Characteristics

over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 3 and Figure 4)

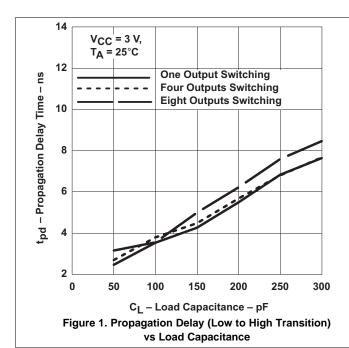
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCA} = 5 V ± V _{CCB} = 2.7 V t	UNIT	
	(INFOT)	(001F01)	MIN	MAX	
t _{PHL}	A	В	1	6.3	ns
t _{PLH}	A	В	1	6.7	115
t _{PHL}	В	Δ.	1	6.1	20
t _{PLH}	В	A	1	5	ns
t _{PZL}	OE	۸	1	9	no
t _{PZH}	OE .	A	1	8.1	ns
t _{PZL}	ŌĒ	В	1	8.8	no
t _{PZH}	OE .	В	1	9.8	ns
t _{PLZ}	OE	A	1	7	no
t _{PHZ}	OE .	^	1	5.8	ns
t _{PLZ}	OE	В	1	7.7	ne
t _{PHZ}	JE	D	1	7.8	ns

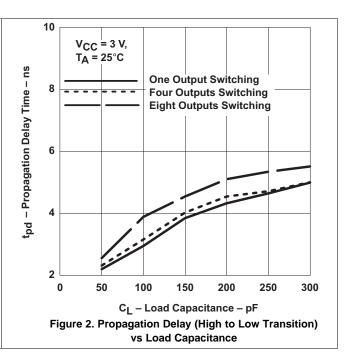
7.10 Operating Characteristics

 V_{CCA} = 4.5 V to 5.5 V, V_{CCB} = 2.7 V to 3.6 V, T_A = 25°C

	PARAMETER		TEST CC	NDITIONS	TYP	UNIT
C	Davier discipation conscitance per transciver	Outputs enabled	6 0	f 10 MHz	39.5	pF
C_{pd}	Power dissipation capacitance per transceiver	Outputs disabled	$C_L = 0$,	f = 10 MHz	5	ρг

7.11 Typical Characteristics

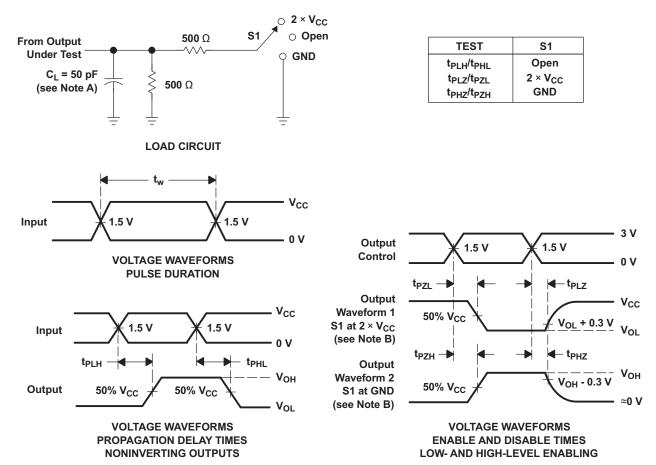






8 Parameter Measurement Information

8.1 A Port



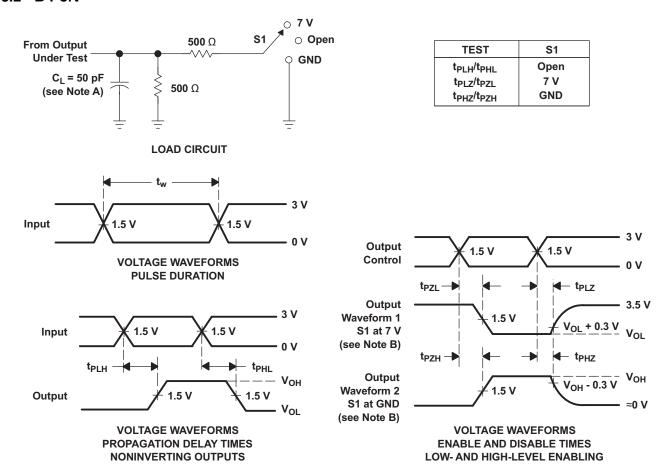
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \,\Omega$, $t_r \leq 2.5 \,\text{ns}$, $t_f \leq 2.5 \,\text{ns}$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



8.2 B Port



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$, $t_r \leq 2.5$ ns, $t_f \leq 2.5$ ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms



9 Detailed Description

9.1 Overview

SN74LVC4245A is an 8-bit (octal) noninverting bus transceiver contains two separate supply rails; B port has V_{CCB} , which is set at 3.3 V, and A port has V_{CCA} , which is set at 5 V. This allows for translation from a 3.3-V to a 5-V environment, and vice versa, designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so the buses are effectively isolated. The control circuitry (DIR, \overline{OE}) is powered by V_{CCA} .

9.2 Functional Block Diagram

To Seven Other Channels

Figure 5. Logic Diagram (Positive Logic)

9.3 Feature Description

- 24 mA drive at 3-V supply
 - Good for heavier loads and longer traces
- Low V_{IH}
 - Allows 3.3-V to 5-V translation

9.4 Device Functional Modes

Function Table

INP	UTS	ODEDATION
OE	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	Х	Isolation



10 Application and Implementation

10.1 Application Information

The SN74LVC4245A device pinout allows the designer to switch to a normal all-3.3-V or all-5-V 20-pin '245 device without board re-layout. The designer uses the data paths for pins 2–11 and 14–23 of the SN74LVC4245A to align with the conventional SN74LVC4245 device's pinout. SN74LVC4245A is a high drive CMOS device that can be used for a multitude of bus interface type applications where output drive or PCB trace length is a concern.

10.2 Typical Application

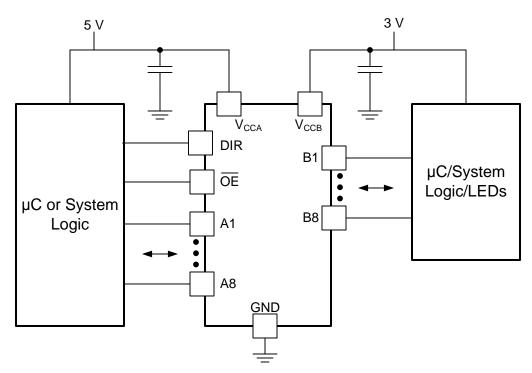


Figure 6. Typical Application Schematic

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

10.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions:
 - For rise time and fall time specifications, see $(\Delta t/\Delta V)$ in the Recommended Operating Conditions table.
 - For specified high and low levels, see (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
- 2. Recommend Output Conditions:
 - Load currents should not exceed (I_O max) per output and should not exceed (Continuous current through V_{CC} or GND) total current for the part. These limits are located in the *Absolute Maximum Ratings* table.
 - Outputs should not be pulled above V_{CC}.
 - Series resistors on the output may be used if the user desires to slow the output edge signal or limit the output current.

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Typical Application (continued)

10.2.3 Application Curves

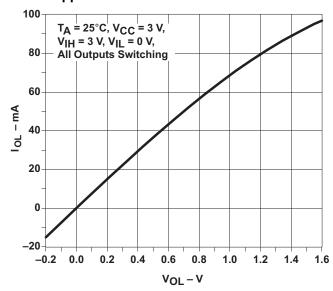


Figure 7. Output Drive Current (I_{OL}) vs LOW-level Output Voltage (V_{OL})

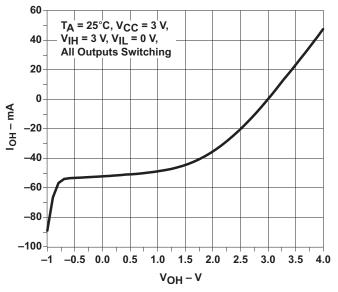


Figure 8. Output Drive Current (I_{OH}) vs HIGH-level Output Voltage (V_{OH})



11 Power Supply Recommendations

11.1 Power-Up Consideration

⁽¹⁾TI level-translation devices offer an opportunity for successful mixed-voltage signal design. A proper power-up sequence always should be followed to avoid excessive supply current, bus contention, oscillations, or other anomalies caused by improperly biased device terminals. Take these precautions to guard against such power-up problems:

- 1. Connect ground before any supply voltage is applied.
- 2. Power up the control side of the device (V_{CCA} for all four of these devices).
- 3. Tie \overline{OE} to V_{CCA} with a pullup resistor so that it ramps with V_{CCA} .
- 4. Depending on the direction of the data path, DIR can be high or low. If DIR high is needed (A data to B bus), ramp it with V_{CCA}. Otherwise, keep DIR low.
- (1) Refer to the TI application report, Texas Instruments Voltage-Level-Translation Devices, literature number SCEA021.

12 Layout

12.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 9 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient.

12.2 Layout Example



Figure 9. Layout Diagram

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13 Device and Documentation Support

13.1 Trademarks

All trademarks are the property of their respective owners.

13.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74LVC4245A





6-Feb-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
SN74LVC4245ADBR	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LJ245A	Samples
SN74LVC4245ADBRE4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LJ245A	Samples
SN74LVC4245ADW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC4245A	Samples
SN74LVC4245ADWE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC4245A	Samples
SN74LVC4245ADWG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC4245A	Samples
SN74LVC4245ADWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	LVC4245A	Samples
SN74LVC4245ADWRE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC4245A	Samples
SN74LVC4245ADWRG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC4245A	Samples
SN74LVC4245APW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LJ245A	Samples
SN74LVC4245APWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LJ245A	Samples
SN74LVC4245APWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LJ245A	Samples
SN74LVC4245APWRE4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LJ245A	Samples
SN74LVC4245APWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LJ245A	Samples
SN74LVC4245APWT	ACTIVE	TSSOP	PW	24	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LJ245A	Samples
SN74LVC4245APWTG4	ACTIVE	TSSOP	PW	24	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LJ245A	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.



PACKAGE OPTION ADDENDUM

6-Feb-2020

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LVC4245A:

Enhanced Product: SN74LVC4245A-EP

NOTE: Qualified Version Definitions:

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

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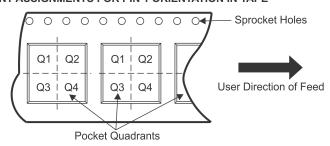
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC4245ADBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
SN74LVC4245ADWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74LVC4245ADWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74LVC4245ADWRG4	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74LVC4245APWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
SN74LVC4245APWT	TSSOP	PW	24	250	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

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*All dimensions are nominal

All difficultions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC4245ADBR	SSOP	DB	24	2000	367.0	367.0	38.0
SN74LVC4245ADWR	SOIC	DW	24	2000	364.0	361.0	36.0
SN74LVC4245ADWR	SOIC	DW	24	2000	350.0	350.0	43.0
SN74LVC4245ADWRG4	SOIC	DW	24	2000	350.0	350.0	43.0
SN74LVC4245APWR	TSSOP	PW	24	2000	367.0	367.0	38.0
SN74LVC4245APWT	TSSOP	PW	24	250	367.0	367.0	38.0



SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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